TOSHIBA Transistor Silicon NPN Epitaxial Type

TPCP8701

Portable Equipment Applications Switching Applications Inverter Lighting Applications

- Small footprint due to small and thin package
- High DC current gain : $h_{FE} = 400$ to 1000 (IC = 0.3 A)
- Low collector-emitter saturation : V_{CE} (sat) = 0.14 V (max)
- High-speed switching : $t_f = 120 \text{ ns}$ (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	100	V	
Collector-emitter voltage		V _{CEX}	80	V	
		V _{CEO}	50	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC (Note 1)	۱ _C	3.0	A	
	Pulse (Note 1)	I _{CP}	5.0		
Base current		Ι _Β	300	mA	
Collector power dissipation (t = 10s)	Single-device operation		1.77	W	
	Single-device value at dual operation	Pc (Note 2)	0.95		
Collector power dissipation (DC)	Single-device operation		0.94		
	Single-device value at dual operation	Pc (Note 2)	0.54	W	
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note 1: Please use devices on condition that the junction temperature is below 150°C.

Note 2: Mounted on FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm^2) Note 3: • on lower left on the marking indicates Pin 1.

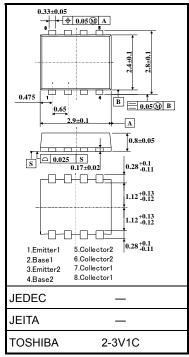
※ Weekly code: (Three digits)



Week of manufacture

(01 for first week of year, continues up to 52 or 53)

Year of manufacture (One low-order digits of calendar year)



Weight: 0.017 g (typ.)

Figure 1. Circuit configuration (Top View)

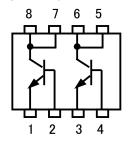
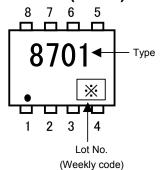


Figure 2. Marking (Note 3)

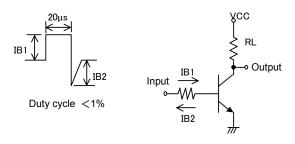


Unit: mm

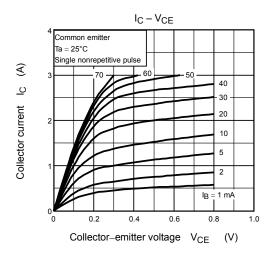
Electrical Characteristics (Ta = 25°C)

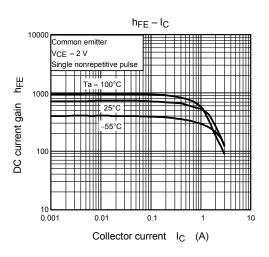
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	$V_{CB} = 100 \text{ V}, I_E = 0$	_	_	100	nA
Emitter cut-off current		I _{EBO}	$V_{EB} = 7 V, I_{C} = 0$	_	_	100	nA
Collector-emitter brakedown voltage		V (BR) CEO	$I_{C} = 10 \text{ mA}, I_{B} = 0$	50	_	_	V
DC current gain		h _{FE} (1)	$V_{CE} = 2 V, I_{C} = 0.3 A$	400	_	1000	
		h _{FE} (2)	$V_{CE} = 2 V, I_{C} = 1 A$	200	_		
Collector-emitter saturation voltage		V _{CE (sat)}	$I_{C} = 1 \text{ A}, I_{B} = 20 \text{ mA}$	_	—	0.14	V
Base-emitter saturation voltage		V _{BE (sat)}	$I_{C} = 1 \text{ A}, I_{B} = 20 \text{ mA}$	_	_	1.10	V
Collector output capacitance		C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{MHz}$	—	13		pF
Switching time	Rise time	t _r	See Figure 3 circuit diagram $V_{CC} \simeq 30 \text{ V}, \text{ R}_L = 30 \Omega$ $I_{B1} = -I_{B2} = 33.3 \text{ mA}$	—	40		ns
	Storage time	t _{stg}		—	500		
	Fall time	t _f		—	120		

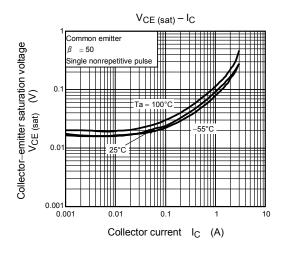
Figure 3. Switching Time Test Circuit & Timing Chart

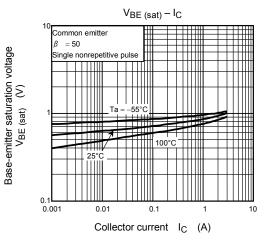


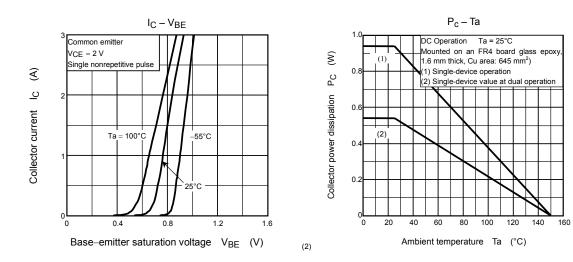
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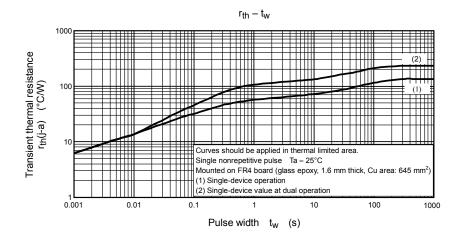


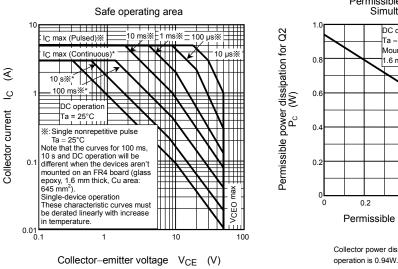




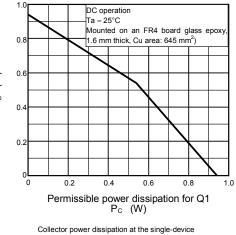








Permissible Power Dissipation for Simultaneous Operation



Collector power dissipation at the single-device value at dual operation is 0.54W.

Collector power dissipation at the dual operation is set to 1.08W.

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